

## CLAIMS

1. A plasma display panel in which a dielectric layer is formed so that the dielectric layer covers a scanning electrode and a sustain electrode formed on a substrate, and in which a protective layer is formed on the dielectric layer,  
5 wherein the protective layer includes carbon and silicon.
2. A plasma display panel as claimed in claim 1, wherein a protective layer is made of magnesium oxide including silicon with  $5 \times 10^{18}$  atoms/cm<sup>3</sup> to  $2 \times 10^{21}$   
10 atoms/cm<sup>3</sup>, and carbon with  $1 \times 10^{18}$  atoms/cm<sup>3</sup> to  $2 \times 10^{21}$  atoms/cm<sup>3</sup>.
3. A plasma display panel as claimed in claim 2, wherein the number of carbon atoms is greater than that of silicon.
- 15 4. A method of manufacturing a plasma display panel in which a dielectric layer is formed so that the dielectric layer covers a scanning electrode and a sustain electrode formed on a substrate, and in which a protective layer is formed on the dielectric layer, wherein a process for forming the protective layer is a process for forming a film using a material for a protective layer, including carbon and  
20 silicon.
5. A method of manufacturing a plasma display panel as claimed in claim 4, wherein a material for a protective layer is magnesium oxide including carbon and silicon; wherein the density of carbon ranges from 5 ppm to 1,500 ppm by weight; and wherein the density of silicon ranges from 7 ppm to 8,000 ppm by  
25 weight.

6. A method of manufacturing a plasma display panel as claimed in claim 4, wherein a material for a protective layer is magnesium oxide including silicon carbide; and wherein the density of silicon carbide ranges from 40 ppm to 12,000 ppm by weight.

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7. A method of manufacturing a plasma display panel in which a dielectric layer is formed so that the dielectric layer covers a scanning electrode and a sustain electrode formed on a substrate, and in which a protective layer is formed on the dielectric layer, wherein carbon and silicon are added in the protective layer  
10 after the protective layer is formed on the dielectric layer.

8. A material for a protective layer of a plasma display panel in which a dielectric layer is formed so that the dielectric layer covers a scanning electrode and a sustain electrode formed on a substrate, and in which a protective layer is  
15 formed on the dielectric layer, wherein the material for a protective layer includes carbon and silicon.

9. A material for a protective layer of a plasma display panel as claimed in claim 8, wherein a material for a protective layer is made of magnesium oxide  
20 including carbon and silicon; wherein the density of the carbon ranges from 5 ppm to 1,500 ppm by weight; and wherein the density of the silicon ranges from 7 ppm to 8,000 ppm by weight.

10. A material for a protective layer of a plasma display panel as claimed in  
25 claim 8, wherein a material for a protective layer is made of magnesium oxide including silicon carbide; and wherein the density of the silicon carbide ranges from 40 ppm to 12,000 ppm by weight.